Technical Data
Data Sheet M2684, Rev. -

**Green Products** 

# MBRF3035CT-G/MBRF3040CT-G/MBRF3045CT-G SCHOTTKY RECTIFIER

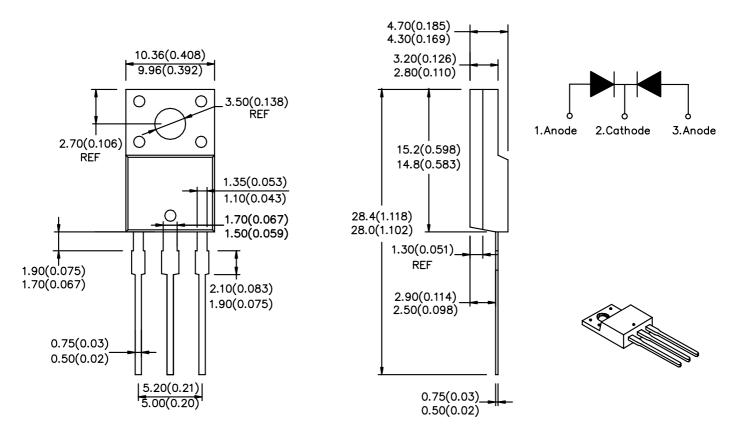
#### **Applications:**

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

#### Features:

- 150 ℃ T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability

#### Mechanical Dimensions: In Inches / mm



**ITO-220AB** 

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# SENSITRON SEMICONDUCTOR

MBRF3035CT-G MBRF3040CT-G MBRF3045CT-G

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## **Maximum Ratings:**

| Characteristics                                      | Symbol             | Condition  |             | Max.          | Uni<br>ts |  |
|--|--------------------|--|-------------|---------------|-----------|--|
| Dools Inverse Veltone                                | V                  |  | 35          | MBRF3035CT-G  | V         |  |
| Peak Inverse Voltage                                 | $V_{RWM}$          | -  | 40          | MBRF3040CT-G  | V         |  |
|  |                    |  | 45          | MBRF3045CT-G  |           |  |
| Max. Average Forward                                 | I <sub>F(AV)</sub> | 50% duty cycle @T <sub>C</sub> =123 °C,                            | 15(per leg) |               | Α         |  |
| Current  |                    | rectangular wave form  | 30          | O(per device) |           |  |
| Peak Repetitive Forward Current (per leg)            | I <sub>FRM</sub>   | Rated V <sub>R</sub> ,square wave,<br>20KHz T <sub>C</sub> =123 °C | 30          |               | Α         |  |
| Max. Peak One Cycle Non-<br>Repetitive Surge Current | I <sub>FSM</sub>   | 8.3 ms, half Sine pulse  | 240         |               | Α         |  |
| Peak Repetitive Reverse<br>Current                   | I <sub>RRM</sub>   | 2.0µsec 1.0KHz   | 1.0         |               | Α         |  |

### **Electrical Characteristics:**

| Characteristics                       | Symbol          | Condition                              | Max.   | Units |
|---------------------------------------|-----------------|--|--------|-------|
| Max. Forward Voltage Drop (per leg) * | $V_{F1}$        | @ 30 A, Pulse, T <sub>J</sub> = 25 °C  | 0.84   | V     |
|                                       | $V_{F2}$        | @ 15 A, Pulse, T <sub>J</sub> = 125 °C | 0.57   | V     |
|                                       |                 | @ 30 A, Pulse, T <sub>J</sub> = 125 °C | 0.72   |       |
| Max. Reverse Current (per             | I <sub>R1</sub> | @V <sub>R</sub> = rated V <sub>R</sub> | 1.0    | mA    |
| leg) *                                |                 | T <sub>C</sub> = 25 °C                 |        |       |
|                                       | $I_{R2}$        | @V <sub>R</sub> = rated V <sub>R</sub> | 40     | mA    |
|                                       |                 | T <sub>C</sub> = 125 °C                |        |       |
| Max. Junction Capacitance             | C <sub>T</sub>  | $@V_R = 5V, T_C = 25  ^{\circ}C$       | 500    | pF    |
| (per leg)                             |                 | f <sub>SIG</sub> = 1MHz                |        |       |
| Typical Series Inductance             | Ls              | Measured lead to lead 5 mm from        | 8.0    | nH    |
| (per leg)                             |                 | package body                           |        |       |
| Max. Voltage Rate of Change           | dv/dt           | -                                      | 10,000 | V/μs  |

Pulse Width < 300µs, Duty Cycle <2%

## **Thermal-Mechanical Specifications:**

| Characteristics                                       | Symbol           | Condition    | Specification       | Units |  |
|---|------------------|--------------|---------------------|-------|--|
| Max. Junction Temperature                             | $T_J$            | -            | -55 to +150         | Ô     |  |
| Max. Storage Temperature                              | T <sub>stg</sub> | -            | -55 to +150         | °C    |  |
| Maximum Thermal Resistance Junction to Case (per leg) | $R_{\theta JC}$  | DC operation | 2.4                 | °C/W  |  |
| Approximate Weight                                    | wt               | -            | 2                   | g     |  |
| Mounting Torque                                       | T <sub>M</sub>   | -            | 6(Min.)<br>12(Max.) | Kg-cm |  |
| Case Style  | ITO-220AB        |              |                     |       |  |

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